

Product Specification

PE4134

Product Description

The PE4134 is a high linearity, passive Quad MOSFET Mixer for PCS & 3G Base Station Receivers, exhibiting high dynamic range performance over a broad LO drive range of up to +20 dBm. This mixer integrates passive matching networks to provide single-ended interfaces for the RF and LO ports, eliminating the need for external RF baluns or matching networks. The PE4134 is optimized for frequency down-conversion using low-side LO injection for PCS & 3G Base Station applications, and is also suitable for up-conversion applications.

The PE4134 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

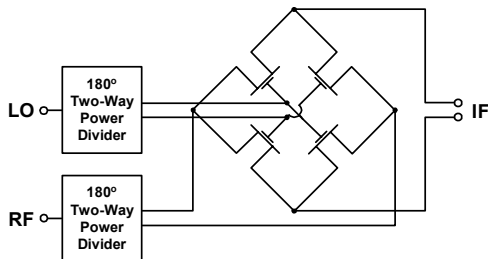


Figure 2. Package Type

6-lead 3x3 mm DFN



Table 1. AC and DC Electrical Specifications @ +25 °C

Parameter	Minimum	Typical	Maximum	Units
Frequency Range:				
LO	1540	--	1740	MHz
RF	1800	--	2000	MHz
IF ¹	--	260	--	MHz
Conversion Loss ²		7.4	8.0	dB
Isolation:				
LO-RF	27	31		dB
LO-IF	27	33		dB
Input IP3				
1.8 GHz	26	29		dBm
1.9 GHz	31	33		dBm
2.0 GHz	28	31		dBm
Input 1 dB Compression		22		dBm

Notes: 1. An IF frequency of 260 MHz is a nominal frequency. The IF frequency can be specified by the user as long as the RF and LO frequencies are within the specified maximum and minimum.

2. Conversion Loss includes loss of IF transformer (M/A COM ETK4-2T, nominal loss 0.7 dB at 260 MHz).

*Test conditions unless otherwise noted: IF = 260 MHz, LO input drive = 17 dBm, RF input drive = 3 dBm.

Figure 3. Pin Configuration (Top View)

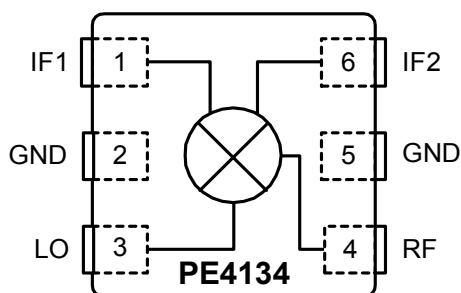


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	IF1	IF differential output
2	GND	Ground connections for Mixer. Traces should be physically short and connect immediately to ground plane for best performance. The exposed solder pad must also be soldered to the ground plane for best performance.
3	LO	LO Input
4	RF	RF Input
5	GND	Ground connections for Mixer. Traces should be physically short and connect immediately to ground plane for best performance. The exposed solder pad must also be soldered to the ground plane for best performance.
6	IF2	IF differential output

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
T_{ST}	Storage temperature range	-65	150	°C
T_{OP}	Operating temperature range	-40	85	°C
P_{LO}	LO input power		20	dBm
P_{RF}	RF input power		12	dBm
V_{ESD}	ESD Sensitive Device		250	V

Absolute Maximum Ratings are those values listed in the above table. Exceeding these values may cause permanent device damage. Functional operation should be restricted to the limits in the DC Electrical Specifications table. Exposure to absolute maximum ratings for extended periods may affect device reliability.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Evaluation Kit

Figure 4. Evaluation Board Layout

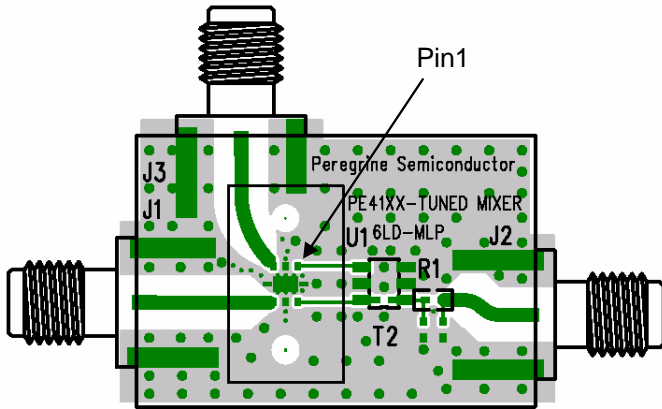


Table 4. Bill of Materials

Reference	Value / Description
T2	M/A Com ETK4-2T
R1	0 Ω
U1	PE4134 MLP Mixer
J1, J2, J3	SMA Connector

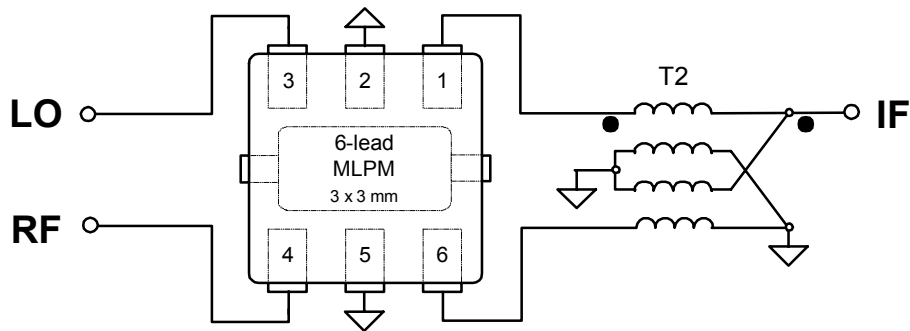
Applications Support

If you have a problem with your evaluation kit or if you have applications questions, please contact applications support:

E-Mail: help@psemi.com (fastest response)

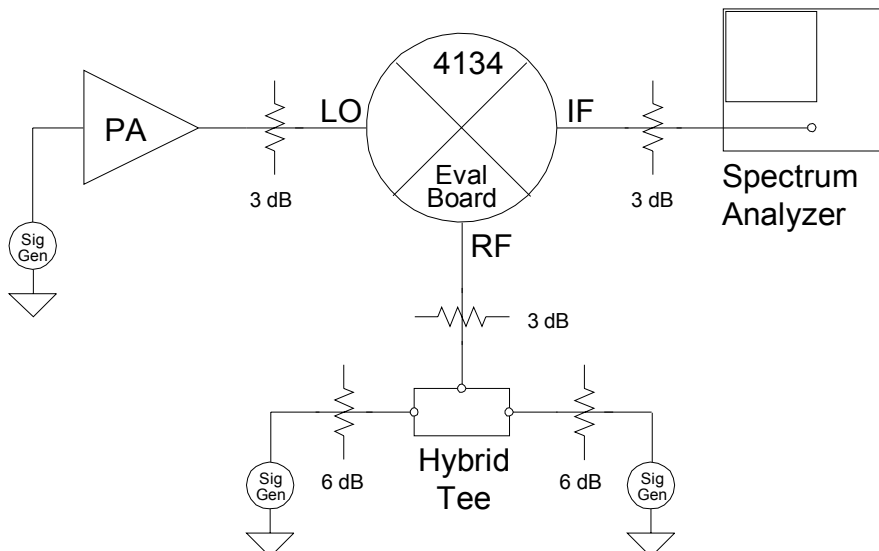
Phone: (858) 731-9400

Figure 5. Evaluation Board Schematic Diagram



T2, M/A-Com E-Series RF 4:1 Transformer, 2.0 – 1000 MHz, ETK4-2T

Figure 6. Evaluation Board Testing Block Diagram, 2-Tone Setup



Typical Performance Data (LO=17 dBm, RF=3 dBm, IF=260 MHz)

Figure 7. Conversion Loss

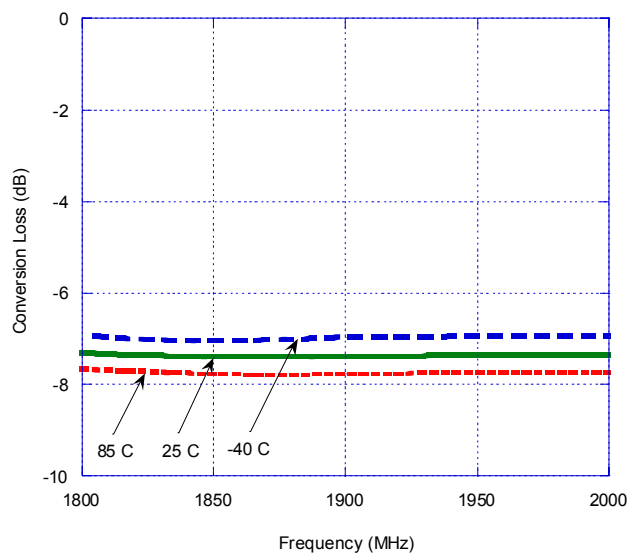


Figure 8. Input 1dB Compression

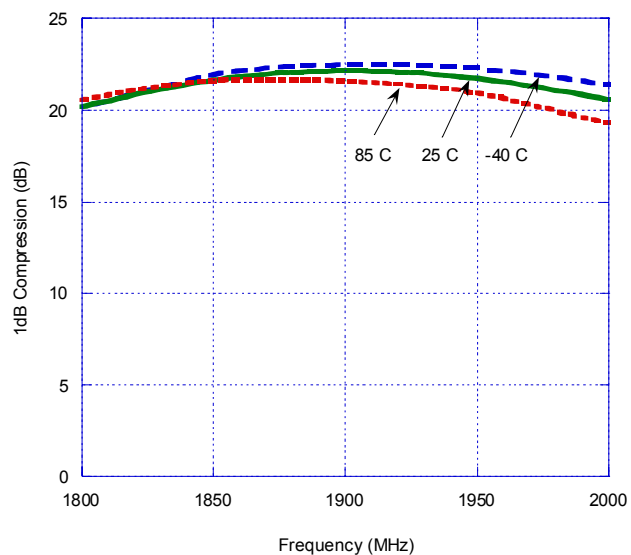


Figure 9. Input IP3

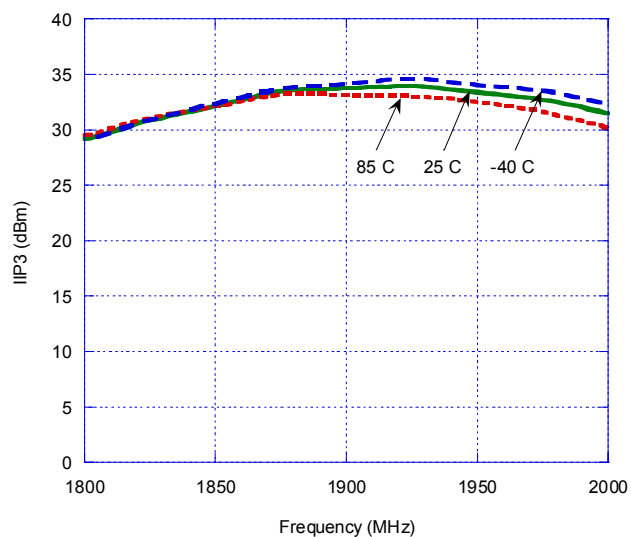
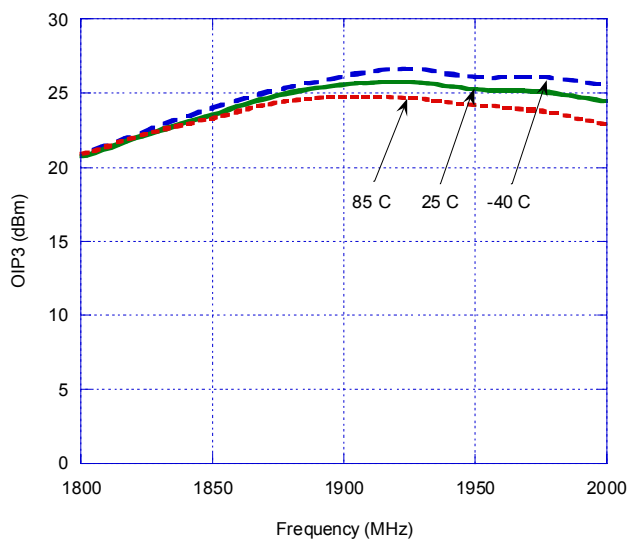
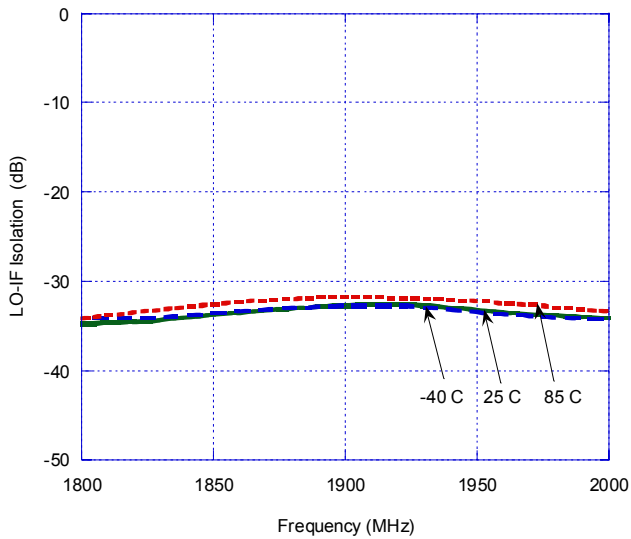
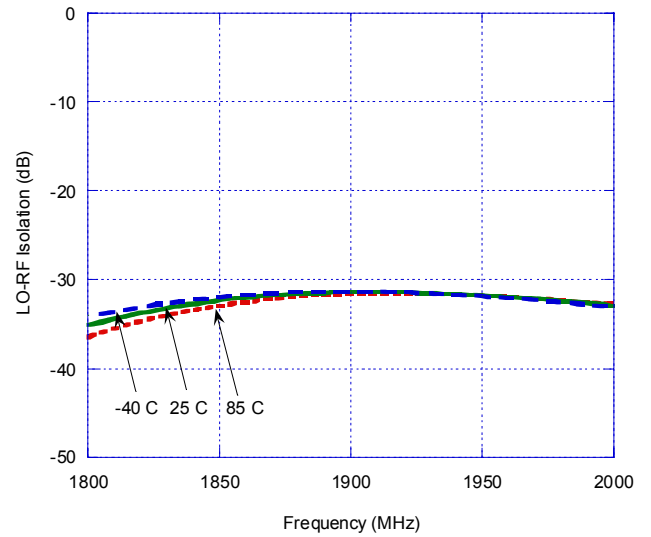
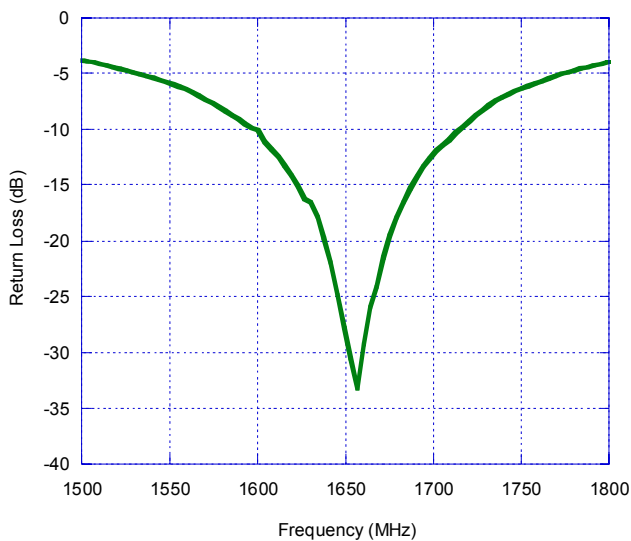
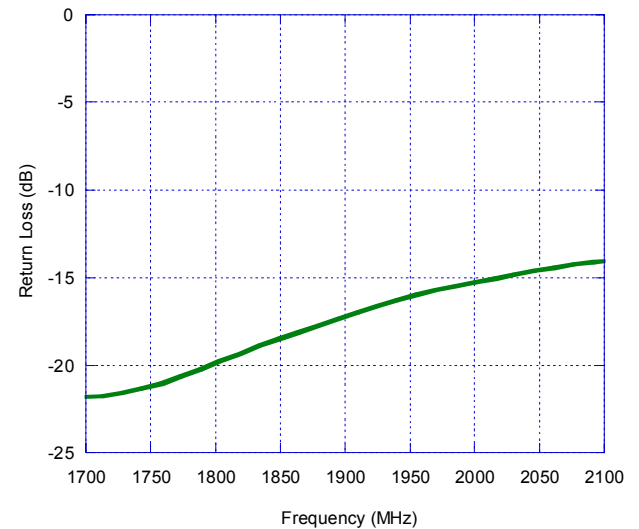


Figure 10. Output IP3



Typical Performance Data (LO=17 dBm, RF=3 dBm, IF=260 MHz)
Figure 11. LO-IF Isolation vs. Frequency

Figure 12. LO-RF Isolation vs. Frequency

Figure 13. LO Port Return Loss @ 25°C

Figure 14. RF Port Return Loss @ 25°C


Typical Performance Data @ +25 °C (RF=3 dBm, IF=260 MHz)

Figure 15. Conversion Loss across LO Power

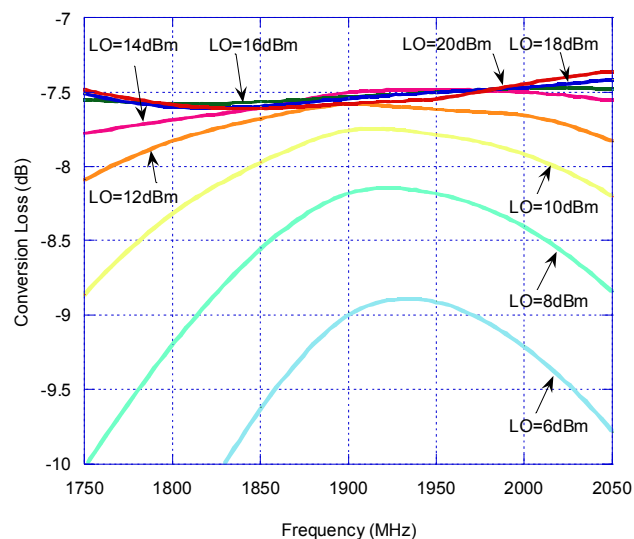


Figure 16. Input IP3 across LO Power

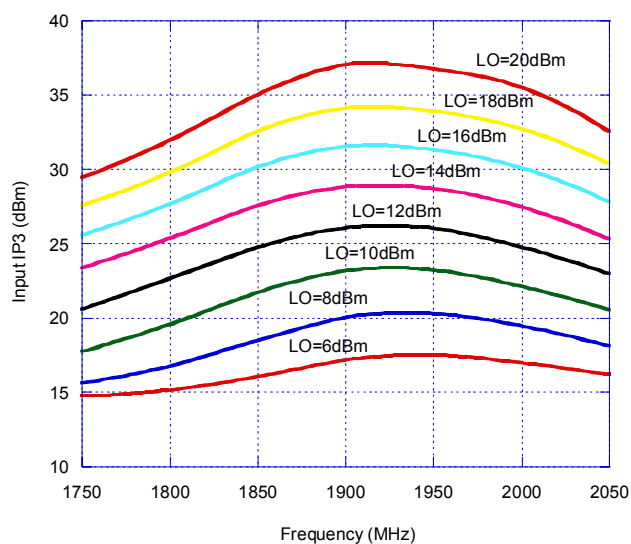


Table 5. Spurious Response

Spurious Response				
	mRF+nLO			
	nLO			
mRF	1	2	3	4
1	5	37	30	50
2	49	55	65	59
3	75	>85	78	80
4	>85	84	>85	>85

Normalized to dB below PIF

(RF=1900 Mhz @ 3 dBm, LO=1640 MHz @ 17 dBm)

Table 6. Spurious Response

Spurious Response				
	mRF+nLO			
	nLO			
mRF	1	2	3	4
1	0	32	22	43
2	57	49	61	62
3	64	71	64	65
4	>85	>85	>85	81

Normalized to dB below PIF

(RF=1900 Mhz @ 3 dBm, LO=1640 MHz @ 17 dBm)

Figure 18. Tape and Reel Specifications

6-lead DFN

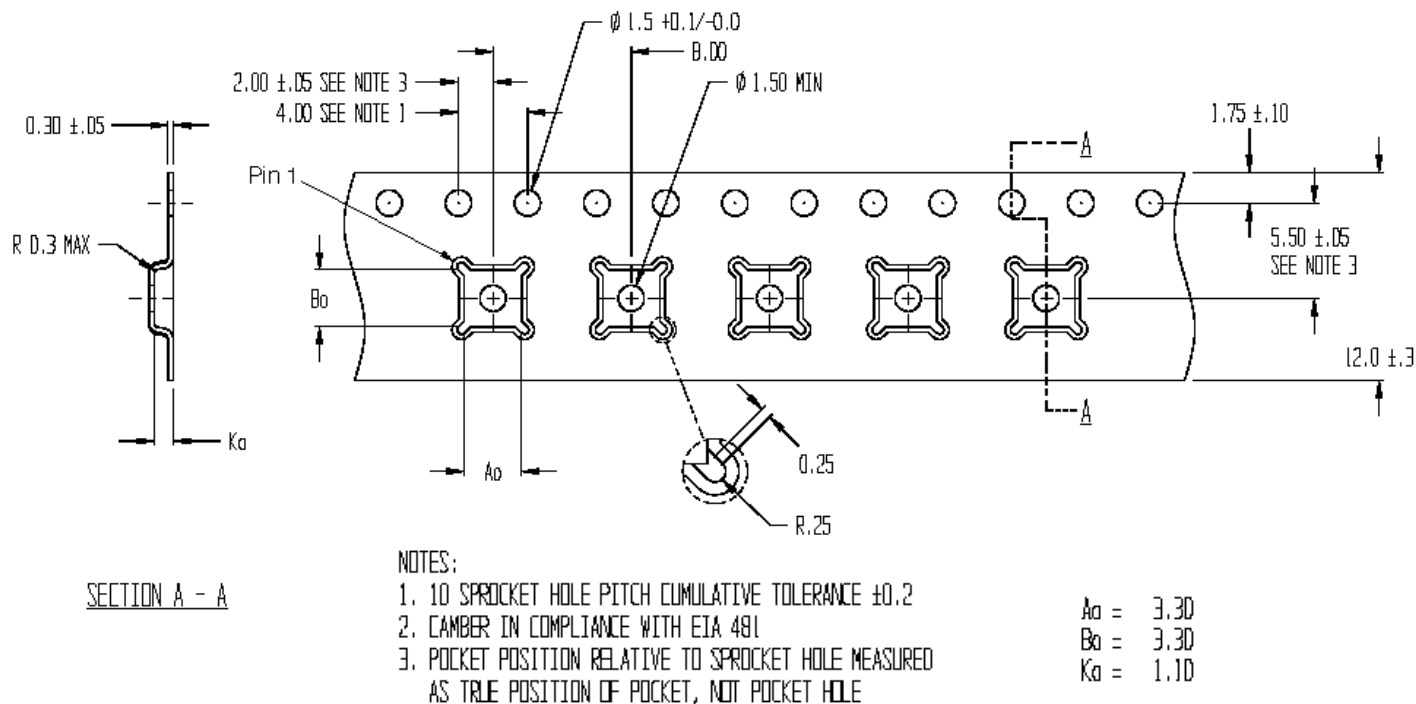


Table 7. Dimensions

Dimension	DFN 3x3 mm
A_0	3.23 ± 0.1
B_0	3.17 ± 0.1
K_0	1.37 ± 0.1
P	4 ± 0.1
W	$8 + 0.3, -0.1$
T	0.254 ± 0.02
R7 Quantity	3000
R13 Quantity	N.A.

Note: R7 = 7 inch Lock Reel, R13 = 13 inch Lock Reel

Table 8. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4134-01	4134	PE4134-06DFN3x3-12800F	6-lead 3x3 mm DFN	12800 units / Canister
4134-02	4134	PE4134-06DFN3x3-3000C	6-lead 3x3 mm DFN	3000 units / T&R
4134-00	4134-EK	PE4134-06DFN3x3-EK	Evaluation Board	1 / Box

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For a list of representatives in your area, please refer to our Web site at: www.psemi.com

Data Sheet Identification

Advance Information

The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a DCN (Document Change Notice).

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